

MBR20100FCT thru 20200FCT

SCHOTTKY BARRIER RECTIFIERS

REVERSE VOLTAGE - 100 to 200 Volts FORWARD CURRENT - 20 Ampere

ITO-220AB

FEATURES

- Metal of silicon rectifier, majority carrier conducton
- Guard ring for transient protection
- Low power loss, high efficiency
- High current capability, low VF
- · High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage, high frequence inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

• Case: ITO-220AB molded plastic • Polarity: As marked on the body • Weight: 0.06 ounces, 1.7 grams • Mounting position : Any

| Dim. | Min. | Max. | | |
|------------------------------|-------|-------|--|--|
| Α | | 10.50 | | |
| В | 2.60 | 3.00 | | |
| С | 6.30 | 6.70 | | |
| D | 2.90 | 3.50 | | |
| Е | 13.10 | 13.90 | | |
| F | | 4.00 | | |
| G | 1.11 | 1.45 | | |
| Н | 0.40 | 0.80 | | |
| I | 5.00 | 5.40 | | |
| J | 4.30 | 4.70 | | |
| K | 2.90 | 3.30 | | |
| L | 8.20 | 9.00 | | |
| М | 2.50 | 2.80 | | |
| N | 0.40 | 0.80 | | |
| All Dimensions in millimeter | | | | |

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

| | | | I | | | |
|---|------------------|-------------|----------|----------|-------|--|
| CHARACTERISTICS | SYMBOL | MBR | MBR | MBR | UNIT | |
| | | 20100FCT | 20150FCT | 20200FCT | | |
| Maximum Recurrent Peak Reverse Voltage | V_{RRM} | 100 | 150 | 200 | V | |
| Maximum RMS Voltage | V _{RMS} | 70 | 105 | | V | |
| Maximum DC Blocking Voltage | V _{DC} | 100 | 150 | 200 | V | |
| Maximum Average Forward Rectified Current | , | 20 | | | А | |
| at T _C =120°C (See Fig.1) | $I_{(AV)}$ | | | | | |
| Peak Forward Surge current | | | | | | |
| 8.3ms single half sine-wave | I _{FSM} | 150 | 1 |) | A | |
| super imposed on rated load (JEDEC METHOD) | | | | | | |
| Voltage Rate of Change (Rated VR) | dw/dt | 10000 | | | dv/us | |
| @I _F =10A T _J =25℃ | V _F | 0.85 | 0.1 | 92 | | |
| Maximum forward @Ip=10A Tp=125°C | | 0.75 | 0. | 75 | v | |
| Voltage (Note 1) @I _F =20A T _J =25°C | | 0.95 | 1. | 00 | | |
| @I;=20A T;=125℃ | | 0.85 | 0. | 86 | | |
| Maximum DC Reverse Current @T=25℃ | , | 0.01 | 0.0 | 008 | mA | |
| at Rated DC Blocking Voltage @T;=125℃ | I_R | 10 | | 5 | | |
| Typical Junction Capacitance (Note 2) | C _J | 250 | | | pF | |
| Typical Thermal Resistance (Note 3) | Rejo | 2.0 | | | °C/W | |
| Operating Temperature Range | Tj | -55 to +150 | | | ਢ | |
| Storage Temperature Range | T _{STG} | -55 to +175 | | | t | |
| NOTES: 1. 300us Pulse Width, 2% Duty Cycle. REV.0, 01Oct-2013 | | | | | | |
| , , , | | | | | | |

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal Resistance Junction to Case.

RATING AND CHARACTERISTIC CURVES MBR20100FCT thru MBR20200FCT

